

A pulsed vacuum arc ion source with a pure boron cathode

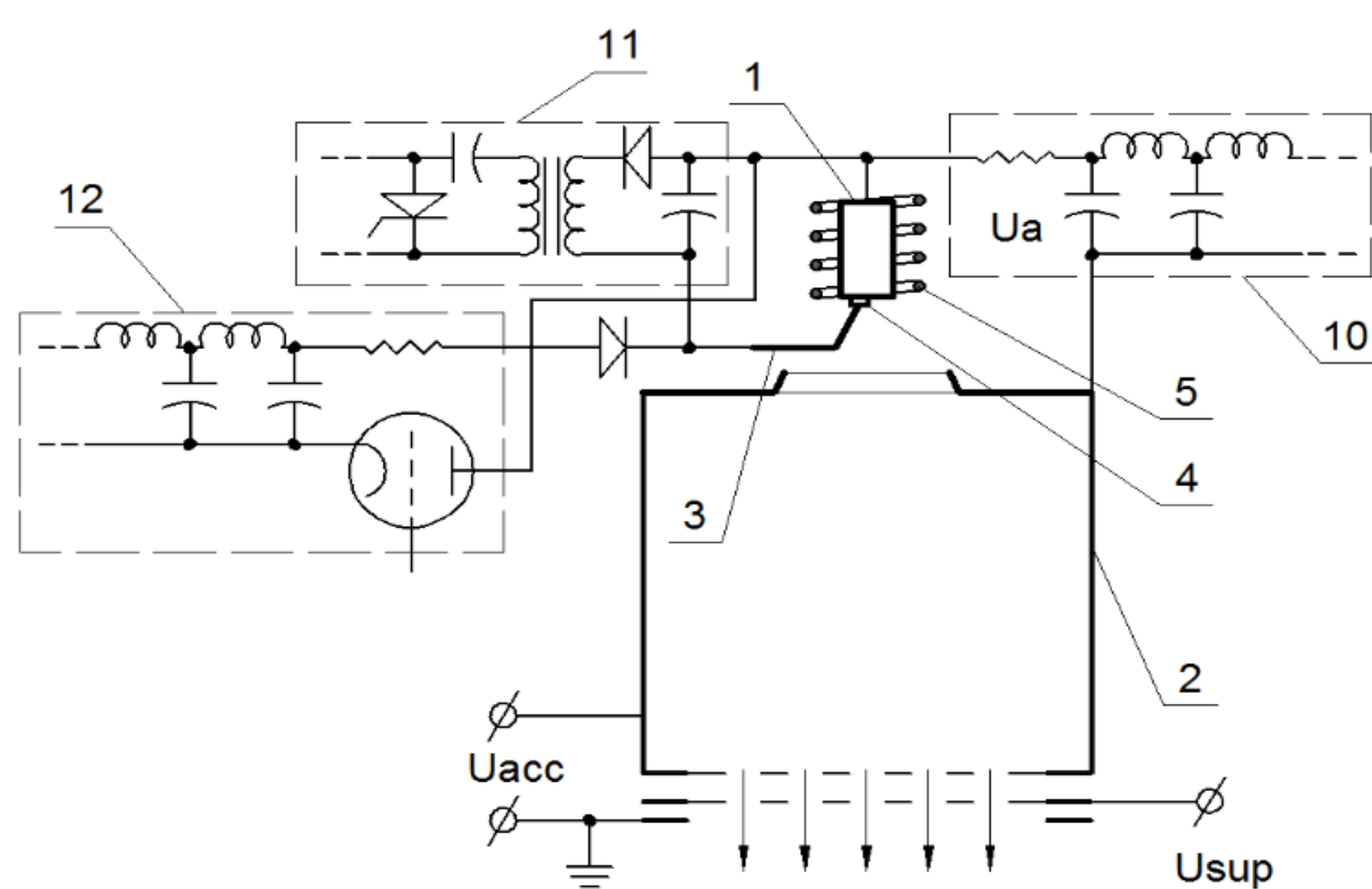
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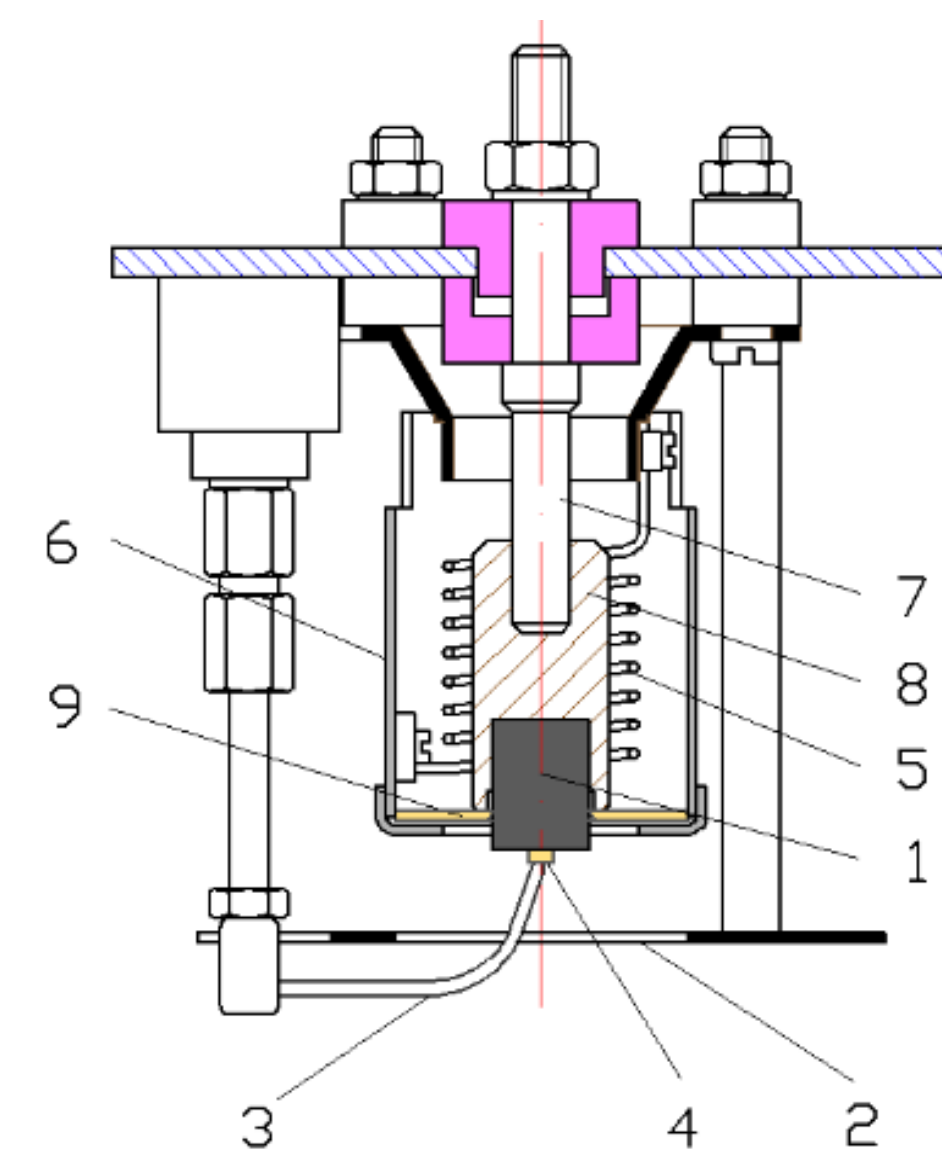
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ABSTRACT

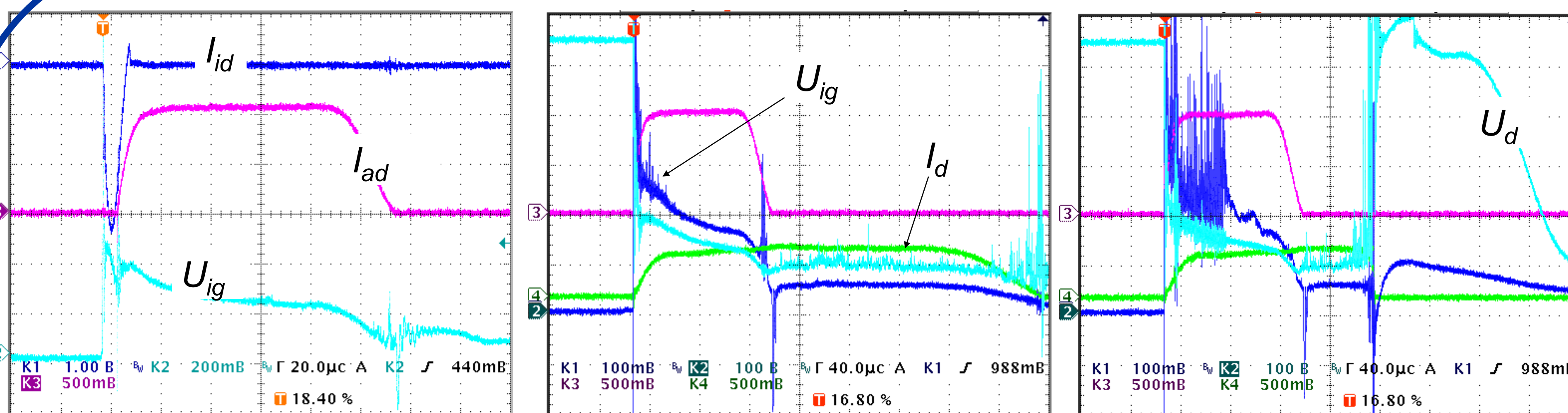
The report presents experimental results on a pulsed vacuum arc ion source with an elemental boron cathode. Boron is a semiconductor having a high specific resistance ($\sim 1.8 \text{ MOhm} \times \text{cm}$) under normal conditions and is difficult to sputter and evaporate [1]. Therefore, for arc ignition with pure boron, it is required to preheat the cathode up to 1000°C . We have designed a high-temperature cathodic unit which uses a special arc triggering technique, provides cathodic arc operation with pure boron, and allows one to decrease the cathode temperature down to 600°C . For an arc current of 100 A with a duration of $100\text{--}300 \mu\text{s}$, the 450-mA beam consists of boron ions in singly and doubly ionized states.



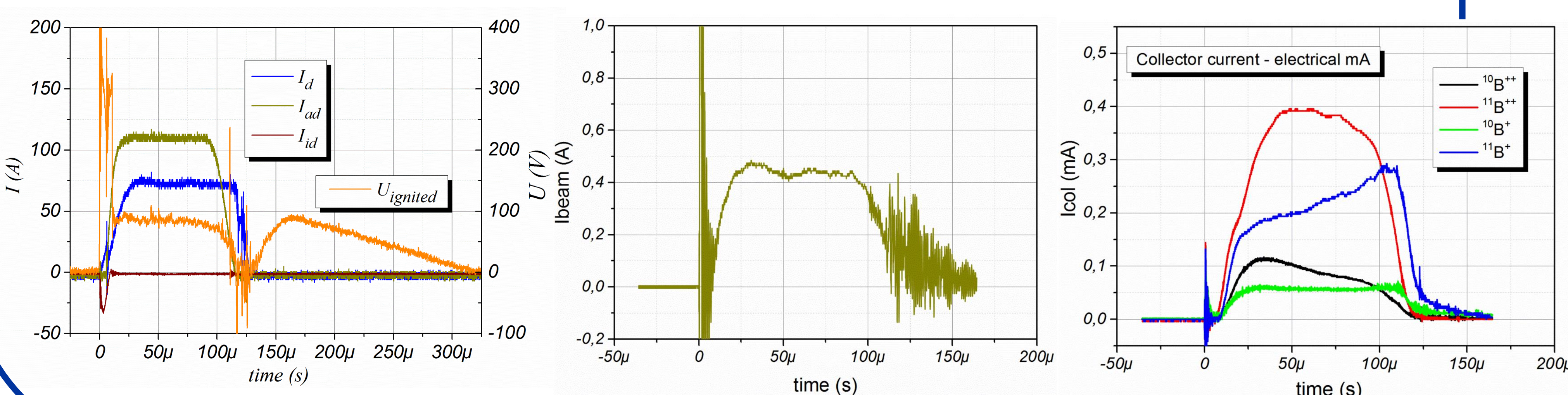
- 1 – boron cathode,
- 2 – hollow anode,
- 3 – igniting electrode,
- 4 – ceramic pellet (alumina or Nb),
- 5 – heater spiral,
- 6 – thermal shield,
- 7 – current lead,
- 8 – ceramic disk (alumina),
- 8 – cathode holder,
- 9 – insulator,
- 10, 11, 12 – power supplies.



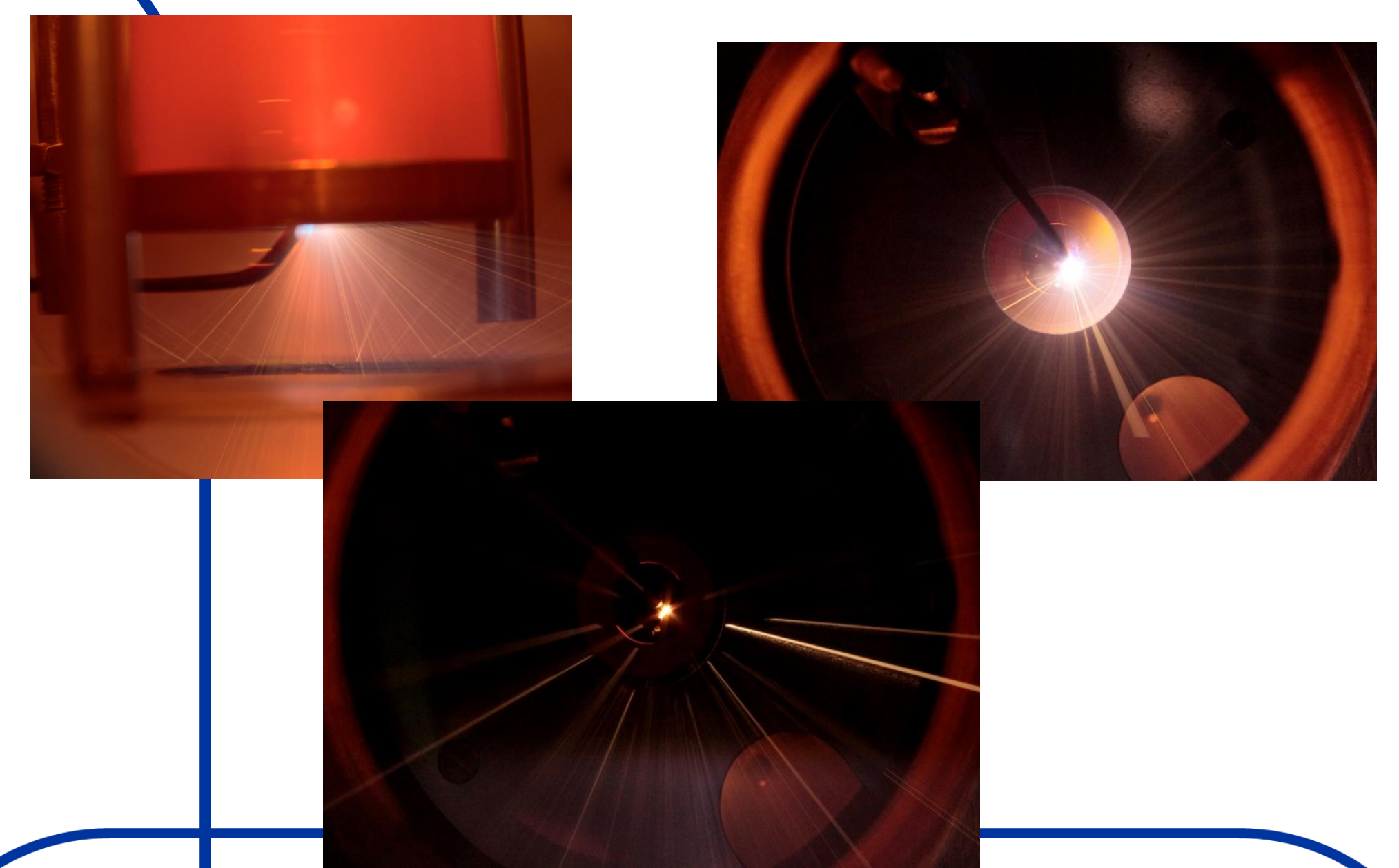
Ion source sketch design and cathode unit (drawing and photography)



Ignited discharge I_{id} , auxiliary discharge I_{ad} and main discharge I_d currents, discharge voltage U_d for different operational modes. Ion beam current I_{beam} , separated ion beam I_{col} and ignited voltage $U_{ignited}$.

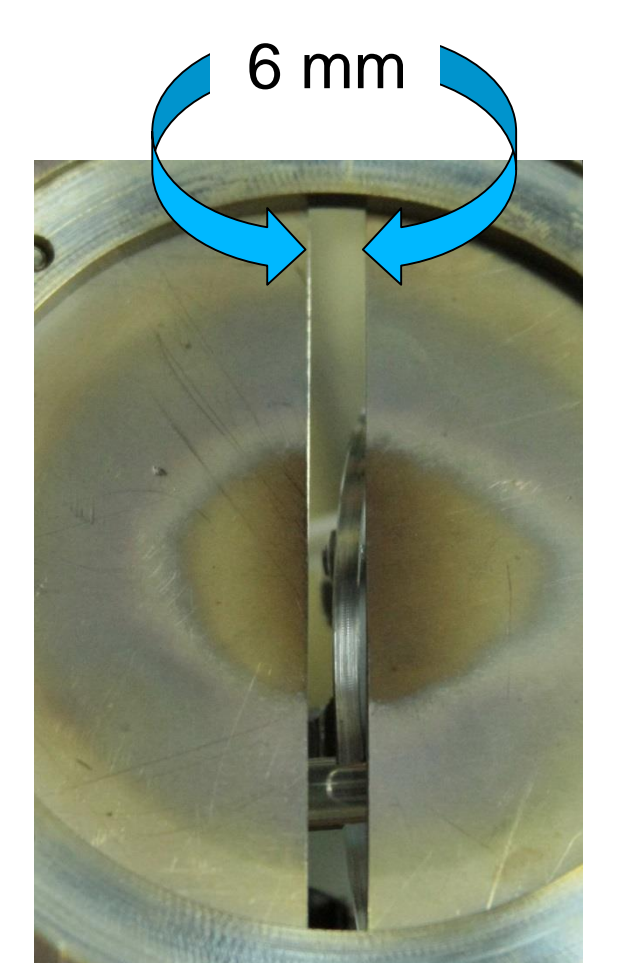


Cathode spot and microdroplet luminescence at different times



A disadvantage of the vacuum arc is the presence in the plasma flow microdroplet fraction.

Ion beam print



Conclusions

The proposed high-temperature cathode unit based on a vacuum arc with pure boron allows one to decrease the cathode temperature for stable arc ignition from 1000°C [1, 2] to $600\text{--}650^\circ\text{C}$, which greatly reduces the energy expended in plasma generation. The cathode unit, which is built in the ion source, provides the generation of a 450-mA beam containing only singly and doubly charged boron ions with near-equal current amplitudes (particle mA) at a discharge current pulse duration of $100 \mu\text{s}$.

References

1. F. Richter, S. Peter, V.B. Filippov et al., IEEE Trans. Plasma Sci. 27, 1079-1083 (1999).
2. J. M. Williams, C.C. Klepper, D. J. Olivers, R. C. Hazelton and J. H. Freeman, "Operation and Applications of the Boron Cathodic Arc Ion Source," in Ion Implantation Technology-2008, AIP Conference Proceedings 1066, edited by E. G. Seeba et al. (American Institute of Physics, Melville, NY, 2008), pp. 469–472.